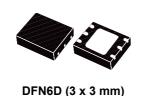


# ST1S03

### 1.5 A, 1.5 MHz adjustable, step-down switching regulator

#### Datasheet - production data



### Features

- Step-down current mode PWM (1.5 MHz) DC-DC converter
- 2% DC output voltage tolerance
- Internal soft-start for STARTUP current limitation and power on delay of 50 - 100 µs
- Typical efficiency: > 70% over all operating conditions
- 1.5 A output current capability
- Not switching quiescent current: max 2.5 mA over temperature range
- Switch  $V_{DS}$ : max. 350 mV at  $I_{SW}$  = 750 mA
- Uses tiny capacitors and inductors
- Available in DFN6D 3 x 3 mm package with exposed pad

### Description

The ST1S03 is a step-down DC-DC converter optimized for powering a low voltage digital core in HDD applications and, generally, to replace the high current linear solution when the power dissipation may cause a high heating of the application environment. It provides up to 1.5 A over an input voltage range of 3 V to 16 V. A high switching frequency (1.5 MHz) allows the use of tiny surface-mount components: as well as the resistor divider to set the output voltage value, only an inductor, a Schottky diode and two capacitors are required. Besides, a low output ripple is guaranteed by the current mode PWM topology and by the use of low ESR SMD ceramic capacitors. The device is thermal protected and current limited to prevent damages due to an accidental short-circuit. The ST1S03 device is available in a DFN6D package.

#### Table 1. Device summary

Order code Package		Packaging
ST1S03PUR	DFN6D (3 x 3 mm)	Tape and reel

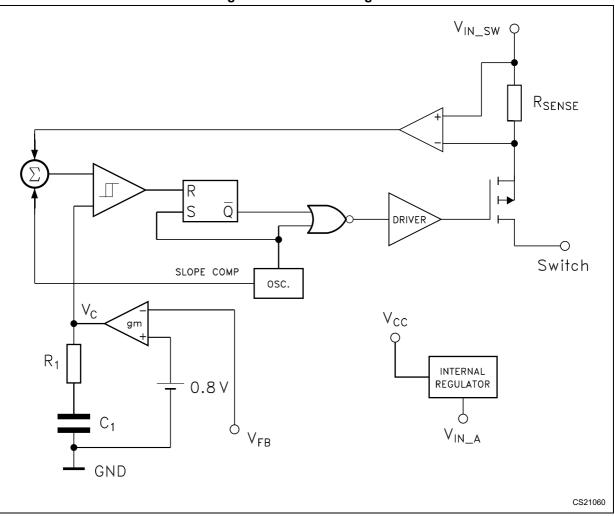
This is information on a product in full production.

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1	Diagram
2	Pin configuration
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### 1 Diagram







# 2 Pin configuration

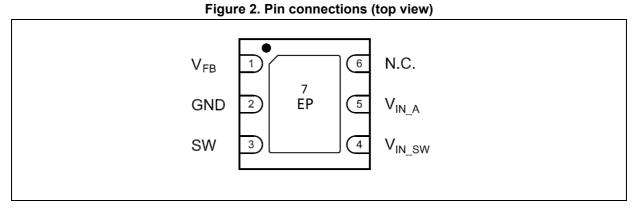


Table 2. Pin description	Table	2. Pin	descri	otion
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Pin no.	Symbol	Name and function
1	V <sub>FB</sub>	Voltage of feedback
2	GND	System ground
3	SW	Output of the internal power switch
4	V <sub>IN_SW</sub>	Power supply for the MOSFET switch
5	V <sub>IN_A</sub>	Power supply for the analog circuit
6	N.C.	Not connected
7	EP	Exposed pad should be connected to GND



### 3 Maximum ratings

Symbol	Parameter	Value	Unit
V <sub>IN_SW</sub>	Positive power supply voltage	-0.3 to 16	V
V <sub>IN_A</sub>	Positive power supply voltage	-0.3 to 16	V
SWITCH voltage	Max voltage of output pin	-0.3 to 16	V
V <sub>FB</sub>	Feedback voltage	2.5	V
I <sub>VFB</sub>	Common mode input voltage	±1	mA
TJ	Max junction temperature	150	°C
T <sub>STG</sub>	Storage temperature range	-25 to 150	°C
T <sub>LEAD</sub>	Lead temperature (soldering) 10 s	300	°C

#### Table 3. Absolute maximum ratings

*Note:* Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

#### Table 4. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction case	10	°C/W
R <sub>thJA</sub>	Thermal resistance junction ambient	55	°C/W



# 4 Electrical characteristics

Table 5. Electrical characteristics (V <sub>IN SW</sub> = V <sub>IN A</sub> = 5 V, C <sub>I</sub> = 4.7 $\mu$ F, C <sub>O</sub> = 22 $\mu$ F, L1 = 3.3 $\mu$ H,
T <sub>J</sub> = 0 to 125 °C, unless otherwise specified. Typical values are referred to 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
FB	Feedback voltage	I <sub>O</sub> = 100 mA	784	800	816	mV
I <sub>FB</sub>	V <sub>FB</sub> pin bias current				600	nA
ا <sub>م</sub>	Quiescent current	No switching			2.5	mA
Ι <sub>Ο</sub>	Output current	V <sub>IN</sub> = 3 V to 16 V	1.5			А
I <sub>MIN</sub>	Minimum output current		1			mA
$%V_{O}/\Delta V_{IN}$	Reference line regulation	V <sub>IN</sub> = 3 V to 16 V		0.032	0.06	$\% V_0/\Delta V_{IN}$
%V <sub>O</sub> /∆I <sub>O</sub>	Reference load regulation	I <sub>O</sub> = 10 mA to 1.2 A		0.0014	0.003	% V <sub>O</sub> /mA
PWM f <sub>S</sub>	PWM switching frequency <sup>(1)</sup>	V <sub>FB</sub> = 0.8 V, T <sub>A</sub> =25 °C	1.2	1.5	1.8	MHz
D <sub>MAX</sub>	Maximum duty cycle			87		%
I <sub>SWL</sub>	Switching current limitation		1.65			А
V <sub>DS</sub>	Switch V <sub>DS</sub>	I <sub>SW</sub> = 750 mA		200	350	mV
E	Efficiency	I <sub>O</sub> = 10 mA to 1.2 A	70			%
T <sub>SHDN</sub>	Thermal shutdown <sup>(1)</sup>		130	150		°C
T <sub>HYS</sub>	Thermal shutdown hysteresis <sup>(1)</sup>			15		°C
$\Delta V_0 / \Delta I_0$	Load transient response <sup>(1)</sup>	$I_O = 100 \text{ mA to } 700 \text{ mA}$ $t_R = t_F \ge 100 \text{ ns}, T_A = 25 ^{\circ}\text{C}$	-5		+5	% V <sub>O</sub>
$\Delta V_O / \Delta I_O at$ $I_O = short$	Short-circuit removal response <sup>(1)</sup>	$I_{O}$ = 10 mA to short, $T_{A}$ = 25 °C			+5	% V <sub>O</sub>

1. Guaranteed by design, but not tested in production.



### 5 Application notes

The ST1S03 is an adjustable current mode PWM step-down DC-DC converter with an internal 1.5 A power switch, housed in a 6-lead DFN 3 x 3 mm package.

It's a complete 1.5 A switching regulator with its internal compensation eliminating an additional component.

The constant frequency, current mode, PWM architecture and stable operation with ceramic capacitors results in a low, predictable output ripple. However, in order to keep the output regulated, the devices goes in pulse skipping mode when a very light load is required.

To clamp the error amplifier reference voltage, a soft-start control block generating a voltage ramp has been implemented. Besides an on-chip power on reset of  $50 = 100 \ \mu s$  ensures the proper operation when switching on the power supply. Other circuits fitted to the device protection are the thermal shutdown blocks which turn off the regulator when the junction temperature exceeds 150 °C typically and the cycle-by-cycle current limiting that provides protection against shorted outputs.

Being the ST1S03 an adjustable regulator, the output voltage is determined by an external resistor divider. The desired value is given by the following equation:

### $V_{O} = V_{FB} [1 + R1 / R2]$

To make the device working, only other four external components are required: a Schottky diode, an inductor and two capacitors. The chosen inductor must be able to not saturate at the peak current level. Besides, its value can be selected keeping in account that a large inductor value increases the efficiency at a low output current and reduces an output voltage ripple, while a smaller inductor can be chosen when it is important to reduce the package size and the total cost of the application. Finally, the ST1S03 device has been designed to work properly with the X5R or X7R SMD ceramic capacitors both at the input and at the output. This kind of capacitors, thanks to their very low series resistance (ESR), minimize the output voltage ripple. Other low ESR capacitors can be used according to the need of the application without invalidating the right functioning of the device. Due to the high switching frequency and peak current, it is important to optimize the application environment reducing the length of the PCB traces and placing all the external components near the device.



# 6 Typical application

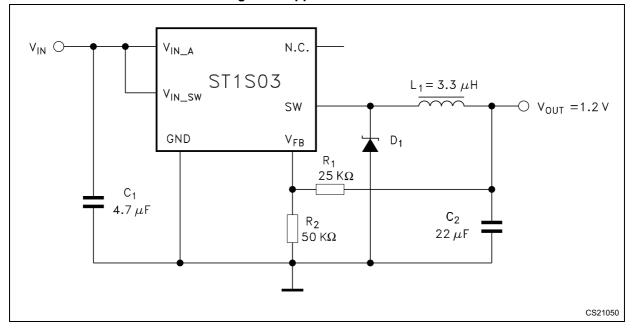
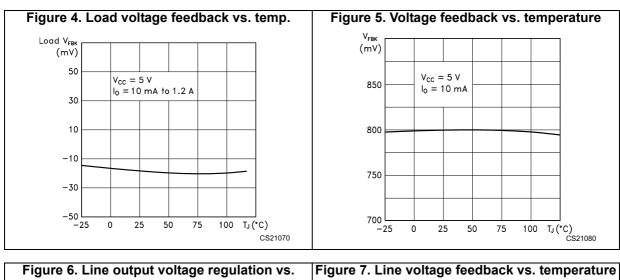


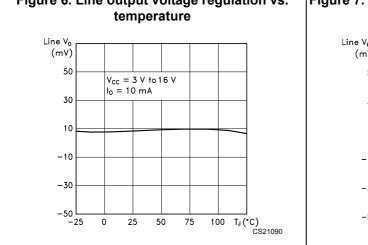
Figure 3. Application circuits

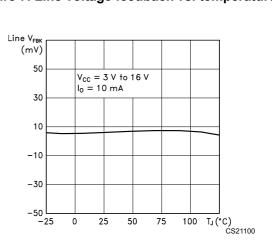


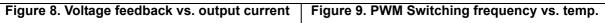
## 7 Typical performance characteristics

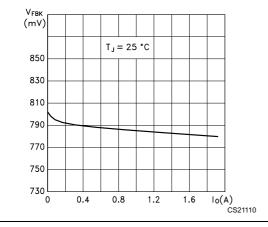


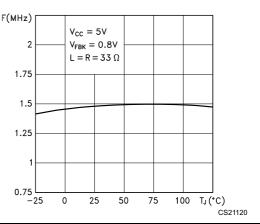
(L1 = 3.3  $\mu$ H, C<sub>I</sub> = 4.7  $\mu$ F, C<sub>O</sub> = 22  $\mu$ F, unless otherwise specified).





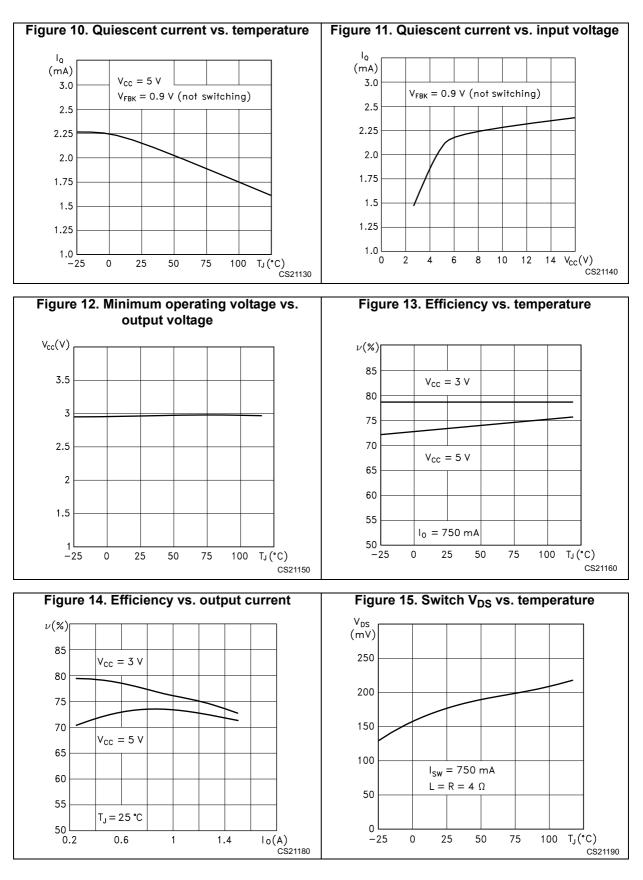




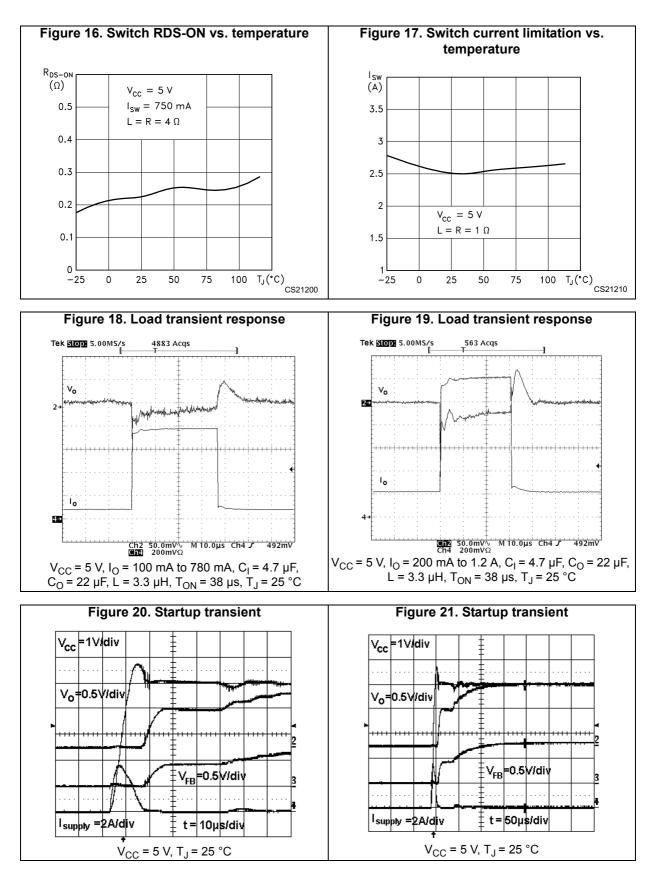




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## 8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK is an ST trademark.



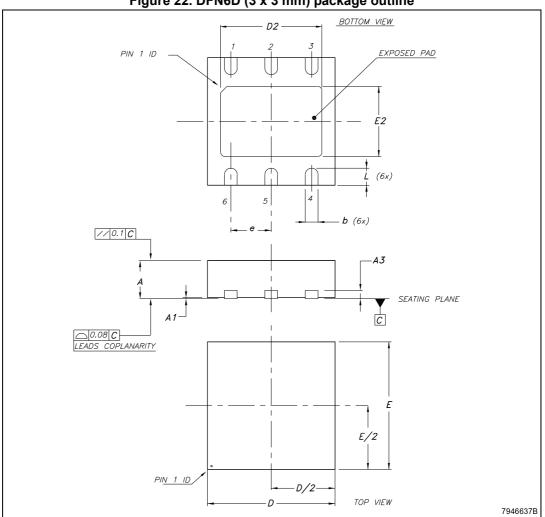


Figure 22. DFN6D (3 x 3 mm) package outline

### Table 6. DFN6D (3 x 3 mm) package mechanical data

Cumb al	Di	imensions (m	m)	Di	ch)	
Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.80		1.00	0.031		0.039
A1	0	0.02	0.05	0	0.001	0.002
A3		0.20			0.008	
b	0.23		0.45	0.009		0.018
D	2.90	3.00	3.10	0.114	0.118	0.122
D2	2.23		2.50	0.088		0.098
E	2.90	3.00	3.10	0.114	0.118	0.122
E2	1.50		1.75	0.059		0.069
е		0.95			0.037	
L	0.30	0.40	0.50	0.012	0.016	0.020



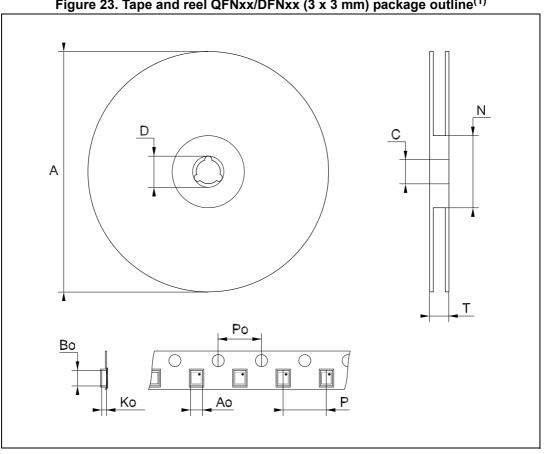


Figure 23. Tape and reel QFNxx/DFNxx (3 x 3 mm) package outline<sup>(1)</sup>

1. Drawing is not in scale.

Table 7. Tape and reel QFNxx/DFNxx (	(3 x 3 mm) p	package mechanical data

Symbol	D	imensions (m	m)	Dimensions (inch)		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			18.4			0.724
Ao		3.3			0.130	
Во		3.3			0.130	
Ко		1.1			0.043	
Po		4			0.157	
Р		8			0.315	



# 9 Revision history

Date	Revision	Changes
11-Nov-2004	1	First Release.
08-Feb-2005	2	Maturity Change.
03-Mar-2005	3	Mistake on Figure 1, $T_J$ is changed 125 ==> 150°C on Table 3.
13-Jul-2005	4	Add new package SO-8 exposed pad.
29-Mar-2007	5	Package SO-8 removed.
07-Mar-2008	6	Removed: package mechanical data DFN6.
14-Nov-2014	7	Updated <i>Table 1: Device summary on page 1</i> (updated Packaging). Updated <i>Figure 2: Pin connections (top view) on page 4</i> (replaced by new figure). Updated <i>Table 2: Pin description on page 4</i> (added row 7). Updated <i>Section 8: Package information on page 12</i> (updated and added titles, updated ECOPACK text, reversed order of <i>Figure 22</i> and <i>Table 6, Figure 23</i> and <i>Table 7</i> , updated headings of <i>Table 6</i> and <i>Table 7</i> ). Minor modifications throughout document.



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